

DIO2372MP8

Ultra Low V_{os}, Low Power Amplifier

Features

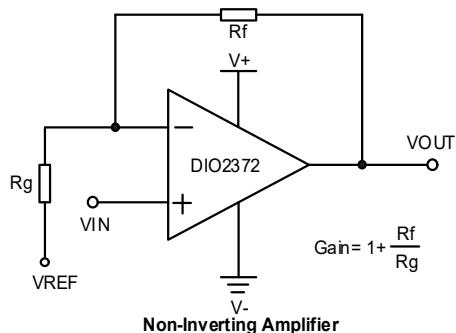
- Ultra low V_{os}: 28μV(Max)
- Low Power: 17.0μA(typ.)
- Unity Gain Stable
- Gain Bandwidth Product: 300kHz(typ.)
- Wide supply range: 2.5V to 5.5V
- Available in MSOP-8 package
- Temperature Range:
 - Industrial: -40°C to 85°C
 - Extended: -40°C to 125°C

Descriptions

DIO2372MP8 is an ultra low V_{os} operational amplifier, with rail-to-rail CMOS input/output and dual channels selectable. DIO2372MP8 has a gain-bandwidth product of 300kHz(typ.), wide operating supply voltage from 2.5V to 5.5V and broad output voltage swing.

DIO2372MP8 consumes ultra low power, with each channel 17.0μA(typ.) of bias current, which makes DIO2372MP8 be ideal for battery powered device, temperature-sense device, etc.

Typical Applications



Applications

- Active Filters
- Data Acquisition
- Portable Equipment
- Test Equipment
- Broadband Communication
- Process Control
- Audio and Video Processing

Ordering Information

Order Part Number	Top Marking		T _A	Package	
DIO2372MP8	DIO2372	Green or RoHS	-40 to 125°C	MSOP-8	Tape & Reel, 3000

Pin Assignments

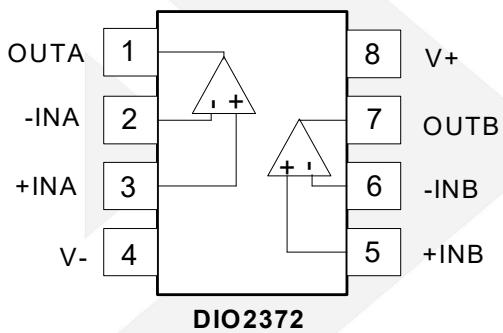


Figure 1 Top View

Pin Description

Pin name	Description
V+	Positive supply
V-	Negative supply
+INX	Positive Input
-INX	Negative Input
OUTX	Output



Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Rating" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameter	Rating	Unit
Supply Voltage (V+ – V-)	7	V
Input Voltage	(V-) -0.3V to (V+) 0.3V	V
Difference Input Voltage	V+ – V-	V
Storage Temperature Range	-65 to 150	°C
Junction Temperature	150	°C
Lead Temperature Range	260	°C
ESD	HBM, JEDEC: JESD22-A114	8
		kV

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation to ensure optimal performance to the datasheet specifications. DIOO does not recommend exceeding them or designing to Absolute Maximum Ratings.

Parameter	Rating	Unit
Supply Voltage	2.5 to 5.5	V
Input Voltage	0 to 5	V
Operating Temperature Range	-40 to 125	°C



DIO2372MP8

Electrical Characteristics

$T_A = 25^\circ\text{C}$, $R_L = 1\text{M}\Omega$ to $V_{CC}/2$, $V_{CM} = 1/2V_{CC}$, unless otherwise specified.

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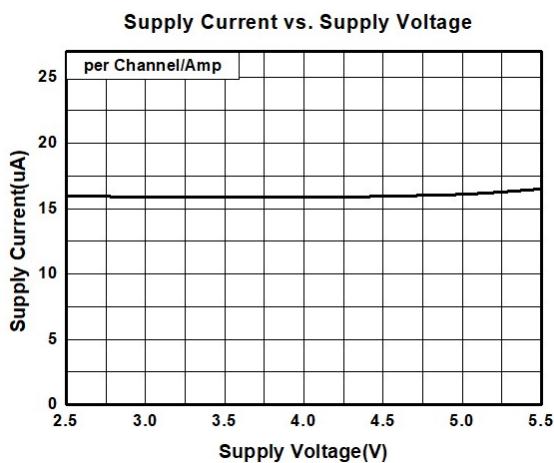
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
INPUT CHARACTERISTICS						
V_{OS}	Input Offset Voltage	$V+=3.3\text{V} / 5\text{V}$	-28		28	μV
I_B	Input Bias Current	$V+=3.3\text{V}$ to 5.5V		1		pA
I_{OS}	Input Offset Current	$V+=3.3\text{V}$ to 5.5V		1		pA
V_{CM}	Common Mode Voltage Range		-0.1		$(V+) +0.1$	V
CMRR	Common Mode Rejection Ratio	$-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		130		dB
A_{OL}	Open Loop Voltage Gain	$R_L=50\text{k}\Omega$, $V_O = 0.1$ to $(V+)-0.1$	80	110		dB
$\Delta V_{OS}/\Delta T$	Input Offset Voltage Drift	$-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		0.05		$\mu\text{V}/^\circ\text{C}$
OUTPUT CHARACTERISTICS						
V_{OH}	Output Voltage High	$R_L=50\text{k}\Omega$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		4.992		V
V_{OL}	Output Voltage Low	$R_L=50\text{k}\Omega$, $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		8		mV
I_{SC}	Output Short Circuit Current	Source I_{SC} , $V+=5\text{V}$		34		mA
		Sink I_{SC} , $V+=5\text{V}$		34		
POWER SUPPLY						
PSRR	Power Supply Rejection Ration		100			dB
I_S	Supply Current per Channel/Amp	$-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		17	27	μA
DYNAMIC PERFORMANCE						
GBP	Gain Bandwidth Product	$C_L=100\text{pF}$, $R_L=1\text{M}\Omega$		300		kHz
SR	Slew Rate	$G=1$, 2V Output Step		160		V/ms
t_S	Setting Time	$G=1$, 2V Output Step		1		ms
Θ_m	Phase Margin			62		Deg
t_r	Overload Recovery Time			40		μs
NOISE PERFORMANCE						
THD	Total Harmonic Distortion	$f=1\text{kHz}$, $4V_{PP}$, $R_L=5\text{k}\Omega$,		0.33		%
e_n	Voltage Noise Density	$f=1\text{kHz}$		70		$\text{nV}/\sqrt{\text{Hz}}$

Specifications subject to change without notice.

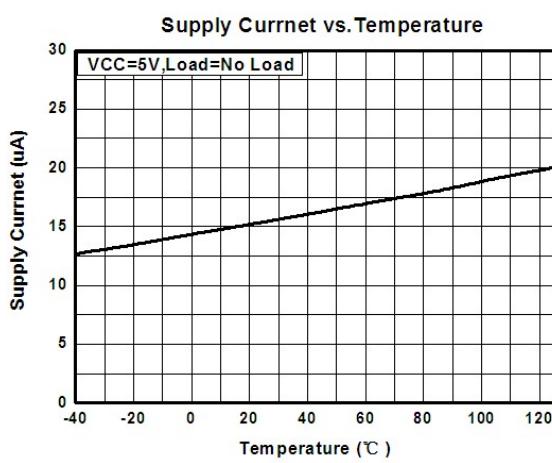
Typical Performance Characteristics

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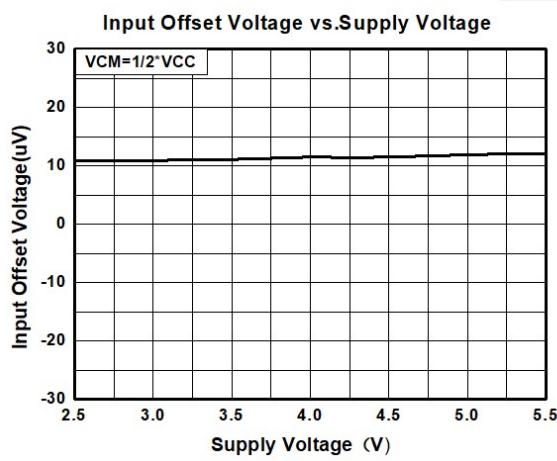
I_S vs. V_{CC}



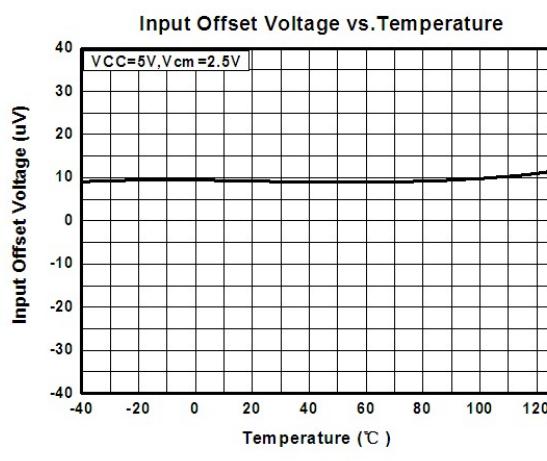
I_S vs. Temperature



V_{OS} vs. V_{CC}

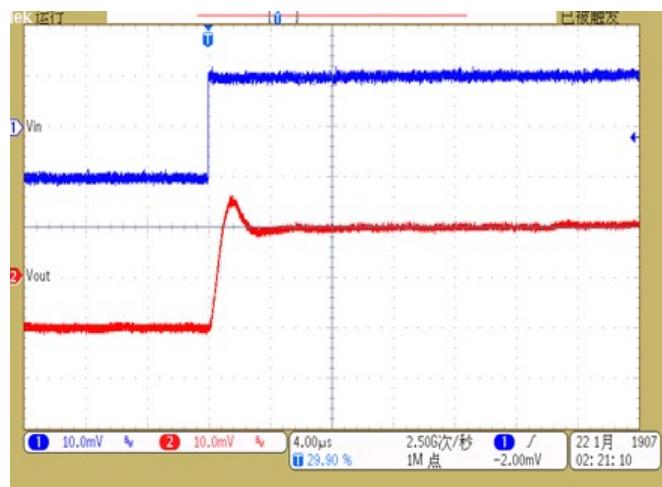


V_{OS} vs. Temperature

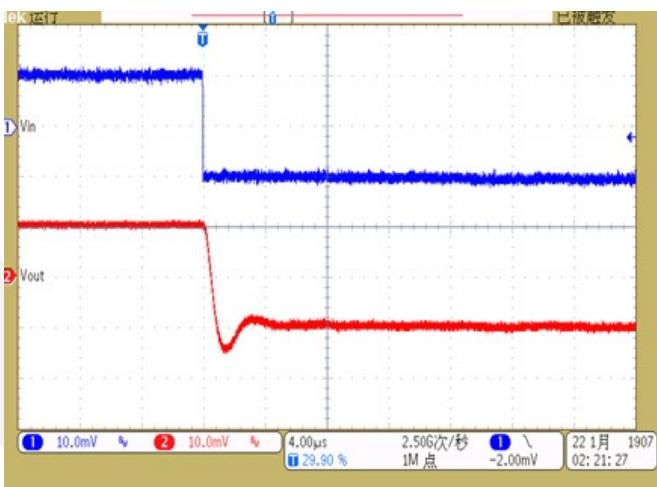


Typical Performance Characteristics (Continue)

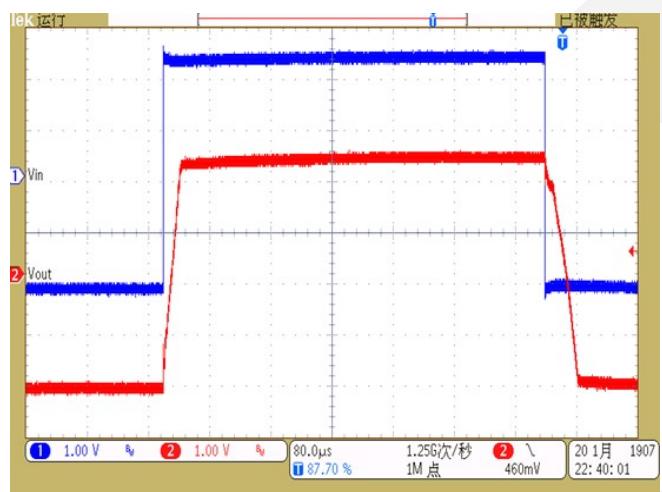
Small-signal Response
($V_{CC}=5V$, $C_L=200pF$)



Small-signal Response
($V_{CC}=5V$, $C_L=200pF$)



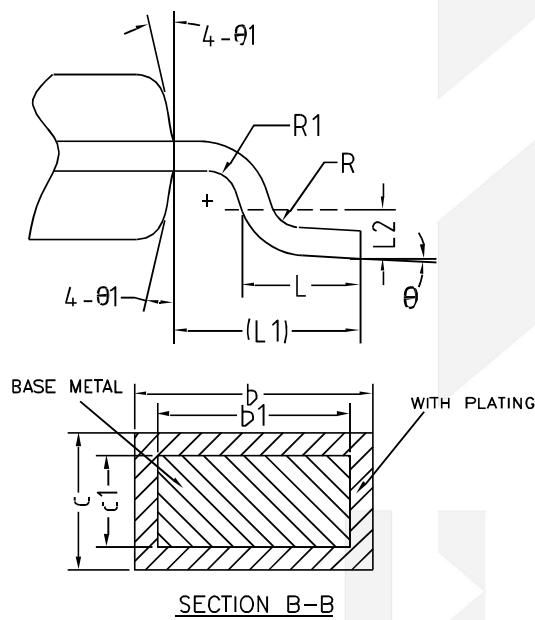
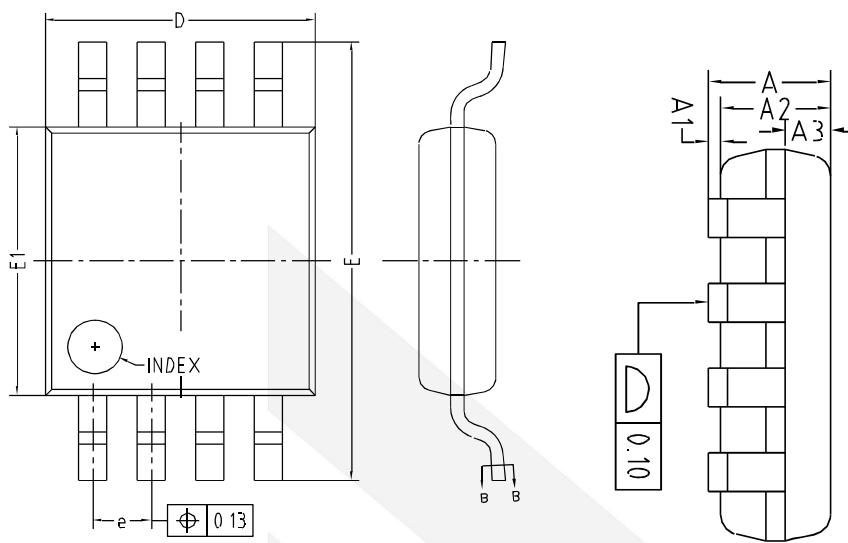
Large-signal Response
($V_{CC}=5V$, $R_L=5.1k\Omega$)



Ultra Low Vos, Low Power Amplifier

Physical Dimensions: MSOP-8

Ultra Low Vos, Low Power Amplifier



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)			
Symbol	MIN	NOM	MAX
A	-	-	1.10
A1	0	-	0.15
A2	0.75	0.85	0.95
A3	0.25	0.35	0.39
b	0.28	-	0.37
b1	0.27	0.30	0.33
c	0.15	-	0.20
c1	0.14	0.15	0.16
D	2.90	3.00	3.10
E	4.70	4.90	5.10
E1	2.90	3.00	3.10
e	0.55	0.65	0.75
L	0.40	0.60	0.80
L1	0.95REF		
L2	0.25BSC		
R	0.07	-	-
R1	0.07	-	-
Θ	0°	-	8°
Θ_1	9°	12°	15°



CONTACT US

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